Nematic topological semimetal and insulator in magic angle bilayer graphene at charge neutrality

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We report on a fully self-consistent momentum space Hartree-Fock calculation of interaction effects on the Moiré flat bands of twisted bilayer graphene, tuned near the magic angle. We focus on the charge neutrality point, where experiments have variously reported either insulating or semimetallic behavior. We find three types of self-consistent solutions with competitive ground state energy (i) inversion $C_2$ breaking insulators with valley Chern number (ii) spin or valley polarized insulators and (iii) rotation $C_3$ symmetry breaking semimetals whose gaplessness is protected by the topology of the Moiré flat bands. We find that the relative stability of these states can be tuned by weak strains that break rotation. Both the nematic semimetal and also, somewhat unexpectedly, the valley-Chern insulator, are stabilized by weak strain. These ground states can explain the semimetallic and insulating behaviors seen at charge neutrality, and the sample variability of their observation. We also find agreement with the results of STM measurements and quantum oscillations near charge neutrality.

Introduction — The discovery of interaction-driven insulating and superconducting behavior in twisted bilayer graphene (TBG) \cite{1,2} has inspired intensive efforts to understand this behavior \cite{3-15} and to find related systems which exhibit similar phenomenology \cite{16-21}. This work has started to bear fruit with several groups announcing similar observations in TBG samples \cite{22-25} as well as other Moiré materials \cite{26-30}. The basic mechanism underlying the enhancement of correlation in these materials is understood to originate from the long-wavelength Moiré pattern leading to quenching of the electron kinetic energy manifested in flat energy bands \cite{31,32}. Nevertheless, the nature of the observed correlated insulating states remains under debate \cite{4,6,8,9}.

Early experiments found clear signature of a correlated insulating state at half-filling \cite{33,1,22}. Later on, insulating ferromagnetic states were also observed at quarter and three-quarter fillings \cite{22,23}. On the other hand, in all these experiments \cite{1,2,22,23} insulating behavior was absent at charge neutrality (CN) where a semimetal was observed instead. In contrast, a recent experiment surprisingly found an insulator at CN whose transport gap was larger than those at 1/2, 1/4 and 3/4 fillings \cite{24}.

On the theory side, it was realized early on \cite{4,34} that a simple Mott picture for the insulating phase is complicated by the band topology which prohibits the construction of localized orbitals describing the flat bands while preserving all the symmetries. An intervalley coherent order \cite{4} was proposed as a candidate for the insulating state at half-filling although in the absence of strong valley dependent dispersion, this order was found to be energetically unfavorable compared to a valley or spin polarized insulator \cite{16,35}, whose energies only differ from each other by a small Hund’s coupling term \cite{16,21}. At charge neutrality, another candidate for an insulating state can be obtained by breaking $C_2T$ symmetry, leading to a gapped valley Hall insulator whose energy is very close to the spin and valley polarized states \cite{9}. In addition, if mixing with the higher bands are allowed, an insulating state can also emerge in the absence of $C_2T$ symmetry breaking \cite{9}. Nematic orders were also discussed in \cite{6,11}.

In this letter, we perform a self-consistent Hartree-Fock mean field analysis for the screened Coulomb interaction projected onto the flat bands to uncover the nature of the symmetry broken states. We focus at the CN point, in the interest of simplicity and because of its pivotal role in determining the entire phase diagram. We will discuss other fillings in subsequent work. We restrict our attention to orders that preserve translation invariance at the scale of the Moiré unit cell. Our results include the expected spin-polarized and valley-polarized insulators, which break no other symmetries. In addition we observe a strong tendency to breaking rotation symmetries. We find a $C_2T$ breaking valley hall insulator and two distinct semimetallic $C_2T$-symmetric $C_3$-breaking phases with comparable energies. These gapless phases are obtained by bringing the two Dirac cones from the Moiré $K$ and $K'$ very close to the $\Gamma$ point. Instead of merging and opening a gap as one might naively expect, the Dirac points remain gapless since they carry the same chirality \cite{4}, a consequence of descending from the Dirac points of graphene from the same valley for the two layers. This prevents them from annihilating, resulting in a gapless semimetallic state whose topological protection arises from the presence of a topological band invariant (non-trivial second Stiefel-Whitney invariant \cite{36}) protected by $C_2T$ symmetry which cannot change for an isolated set of bands. At the same time, the nontrivial invariant minimally requires a pair of bands, resulting in topologically protected band contacts. Thus, the metallic nature at CN in this scenario is intimately tied to the topological properties of the magic angle flat bands.

We investigate the effect of small explicit $C_3$ symmetry breaking which can arise in real samples due to strain \cite{20}, and show that it strongly influences the competition between different symmetry broken phases, favoring one of the $C_3$-breaking semimetallic phases together with the insulating $C_2T$-breaking valley Hall state. Surprisingly, the latter exhibits a strong susceptibility to $C_3$ symmetry breaking, developing a large $C_3$-breaking component in response to small explicit $C_3$ symmetry breaking. The energies of the insulating $C_2T$-breaking and the semimetallic $C_2T$-preserving states approach each other quickly as the value of the $C_3$-breaking parameter is increased.
Our results suggest that in the presence of very small explicit $C_3$ symmetry breaking which is likely to exist in experiments, there are two candidate ground states with very close energies at CN which both strongly break $C_3$: a $C_2 T$-breaking valley Hall insulator and a $C_2 T$-preserving semimetal. The competition between these two phases is likely to be settled by small sample-dependent details, potentially explaining why an insulator is observed in some samples while a semimetal is observed in others.

Complementary information about the states at the CNP is provided by STM measurements which provided compelling evidence for $C_3$ symmetry breaking at CN [37,39]. We compare our theoretical predictions for the density of states (DOS) and spatial variation of the local filling fraction to those measured in STM [37,39] and show they are in good agreement for the $C3$ breaking semimetal.

Recently, it was shown theoretically that a particular variety of weak $C_3$ breaking [40] can robustly reproduce the unusual pattern of Landau levels observed in TBG [22,24,30]. Here we also examine the quantum oscillations signatures and argue that even in the strongly $C_3$ broken nematic semimetal, they are consistent with the observed pattern of Landau levels [1,22,40].

**Problem setup** — The single-particle physics is described by the Bistritzer-MacDonald (BM) model [31,32], which employs a continuum approximation close to $\theta=0$. The Hamiltonian for the $K$ valley is given by:

$$
\mathcal{H}_+ = \sum_l \sum_k \frac{f_l^\dagger (k) h_l (\theta/2) f_l (k)}{} + \left[ \sum_k \sum_{i=1}^3 f_i^\dagger (k + q_i) T_i f_i (k) + h.c. \right].
$$

Here, $l = t/b \simeq \pm 1$ is the layer index, and $f_l (k)$ is the $K$-valley electron originated from layer $l$. $h_l (\theta)$ is the monolayer graphene $K$-valley Hamiltonian with twist angle $\theta$ (see supplementary material for details) and $q_1$ is defined as $K_b - K_t$ with $K_t$ denoting the $K$-vector of layer $l$. $q_2 = O_3 q_1$ is the counterclockwise $2\pi/3$ rotation of $q_1$, and $q_3 = O_3 q_2$. Finally, the interlayer coupling matrices are given by

$$
T_j = \begin{pmatrix}
w_0 & w_1 e^{-(j-1) \frac{2\pi}{3}} & w_0 \\
w_1 e^{-(j-1) \frac{2\pi}{3}} & w_1 & w_0 \\
w_0 & w_0 & w_0
\end{pmatrix},
$$

with $w_0$ and $w_1$ denoting intrasublattice and intersublattice hopping, respectively. Due to lattice relaxation effects, which shrink the AA regions relative to the AB regions, the value of $w_0$ at the magic angle is about 75% of $w_1$ [31,42]. Throughout this work, we will use the values $w_1 = 110$ meV and $w_0 = 82.5$ meV. Explicit $C_3$ symmetry breaking is implemented via the substitution $T_j \rightarrow (1 + \beta) T_j$ [40].

To study possible correlated insulating states, we employ a momentum-space self-consistent Hartree-Fock mean field theory. The momentum-space description allows us to focus on the pair of flat bands at CN, thereby evading the difficulties associated with the real space Wannier obstruction rooted in the fragile topology of these bands [4,32,43]. Restricting the analysis to the flat bands has the advantage of limiting the number of possible self-consistent solutions, making it more likely to numerically find all of them in addition to making it easier to understand and analyze the resulting phases. However, this approach neglects possible symmetry-broken states involving higher bands discussed in Ref. [9] which may be relevant since the interaction strength is comparable to the bandgap.

The Hartree-Fock (HF) mean field theory is defined in terms of the projector

$$
P_{\alpha,\beta}(k) = \{c^\dagger_{\alpha}(k) c_{\beta}(k)\}, \quad P(k)^2 = P(k) = P(k)^\dagger, \quad (3)
$$

where $\alpha = (n, \tau, s)$ is a combined index for band, valley and spin, respectively, and $c_{\alpha}(k)$ is the annihilation operator for an electron in a state labelled by $\alpha$ at momentum $k$. For a gapped or semimetallic phase at CN, $P$ satisfies $\text{tr} \, P(k) = 4$.

The HF mean field Hamiltonian has the form

$$
\mathcal{H}_{MF} = \sum_k \left\{ c(k)^\dagger \{ \xi(k) + h_{HF}(k) \} c(k) - \frac{1}{2} \text{tr} \, h_{HF}(k) P^T(k) \right\}. \quad (4)
$$

Here, $(c(k)$ is a column vector in the index $\alpha$, $\xi(k)$ denotes the single particle energies and $h_{HF}(k)$ is given by

$$
h_{HF}(k) = \frac{1}{A} \sum_G V_G \Lambda_G (k, k) \sum_{k'} \text{tr} \, P(k') \Lambda_G^\dagger (k', k') - \frac{1}{A} \sum_{G, k'} V_{G+k'-k} \Lambda_G (k, k') P^{T T}(k') \Lambda_G^\dagger (k, k'), \quad (5)
$$

where $A$ is the total area. The $k'$ summation ranges over the first Brillouin zone whereas the $G$ summation is over reciprocal lattice vectors. $V(q)$ is the interaction potential which we take to be a single-gate-screened Coulomb interaction $V(q) = \frac{e^2}{2 \epsilon_{\text{seq}}} (1 - e^{-2q_d \epsilon})$ with dielectric constant $\epsilon = 7$ and screening length equal to the gate distance $d_s \approx 40$ nm.

The HF self-consistency analysis starts by proposing an Ansatz for the projector $P(k)$, then substituting in the Hamiltonian (3) which is then used to compute the new projector. This procedure is iterated until convergence is achieved.

One important subtlety in the HF approach is that the band structure depends on the filling even without symmetry breaking. This follows from the fact that the form factor matrix $\Lambda_q (k)$ is not diagonal in the band index for $q \neq 0$ since $\xi$-vectors from different bands are not orthogonal at different momenta. In addition, the Hartree term contains a trace over
all filled bands which also affects the dispersion of the empty bands. This means that the band structure obtained from the BM model is only valid at a specific filling which determines the references point for out analysis. At this point, it will be assumed that interaction effects are already included in the parameters of the effective model which can be obtained by fitting to ab initio calculations or comparing to STM data away from the magic angles [38]. A natural choice of the reference point, which we adopt throughout this letter, is the CN point.

Using CN as our reference point implies that the bands at empty or full filling should include some HF corrections leading to a modified band structure. The resulting DOS is shown in Fig. [3]. We notice that the separation between the two peaks in the DOS is about 10-15 meV in agreement with the measured DOS in STM experiments [38]. Thus, our approach provides an explanation for the discrepancy between the experimentally measured peak separation and the expectation based on the BM model whose bandwidth close to the magic angle is much smaller (1-3 meV).

**Symmetry-broken phases.** — The interacting TBG Hamiltonian is characterized by the following symmetries [4]: spinless time-reversal $T$, SU(2) spin rotation, U(1) valley charge conservation and $C_6$ symmetry [44]. Of these, only spin rotation, $C_3$ and $C_2T$ act within each valley. At integer filling, different correlated insulating phases can emerge by breaking some of these symmetries. Time-reversal symmetry is broken by valley polarized (VP) states, where the filling of the two valleys is different. Spin rotation symmetry is broken by spin polarization (SP) leading to ferromagnetic order. U(1) valley charge conservation is broken in the presence of intervalley coherent (IVC) superposition of states from the two valleys. $C_2$ symmetry is broken by sublattice polarization which gaps out the Dirac points at the Moiré $K$ and $K'$ points.

Breaking $C_3$ symmetry alone does not generally lead to a gapped phase since it only moves the Dirac points away from the Moiré $K$ and $K'$ without-gap them out. This is a consequence of the topology of the two flat bands captured by the second Stiefel-Whitney invariant $w_2$ [36]. This invariant is protected by $C_2T$ and only depends on the flat band eigenstates which are unaffected by any symmetry breaking that does not involve other bands (which is the main assumption in this work). The non-trivial $w_2$ invariant implies that the two Dirac points cannot be removed without breaking $C_2T$. This can be understood by noting that the two Dirac points at the Moiré $K$ and $K'$ have the same chirality (since they descend from the graphene $K$ point for the top/bottom layer) and therefore cannot annihilate each other.

Before presenting the numerical results, let us make the following observations. First, it is relatively easy to show that a state with uniform full spin or valley polarization is always a self-consistent solution to the HF equations at CN for sufficiently narrow bands. These two states have the same energy in the absence of Hund’s coupling [16][21] and we can only focus on one of them. The IVC state is known to have higher energy than SP/VP states for isolated bands with non-vanishing valley Chern number [16]. In the presence of $C_2T$ symmetry breaking, this is clearly the case in TBG [35]. However, even in the absence of $C_2T$ symmetry breaking, the IVC is expected to have significantly larger energy than SP/VP. This can be rigorously established in the chiral limit where the intrasublattice interlayer hopping is switched off ($w_0 = 0$) [45] as shown in the supplemental material. This motivates us to exclude the IVC order in our numerical analysis i.e. we assume that U(1) valley symmetry is unbroken.

**Results.** — The results for the self-consistent HF analysis are provided in Fig. [4] showing the energies of the different solutions as a function of the $C_3$ symmetry breaking parameter $\beta$. There are three gapped solutions corresponding to spin-polarized (SP), valley-polarized (VP) and $C_2T$-breaking valley Hall insulators ($C_2TI$) with valley Chern number $\pm 1$ per spin. The latter does not break $C_3$ when $\beta = 0$ but develops a large $C_3$ breaking component for $\beta \neq 0$. The extent of $C_3$ symmetry breaking can be quantified by defining

$$\chi_{C_3} = \frac{1}{N} \sum_{k} (1 - |\langle \psi_{C_3,k} | C_3 | \psi_{k} \rangle|^2),$$

which vanishes for any $C_3$-symmetric state. Here, $|\psi_{k}\rangle$ are the occupied single-particle eigenstates of the HF Hamiltonian with momentum $k$ (for a given flavor). The value of $\chi_{C_3}$ for the $C_2TI$ state is shown in Fig. [4] as a function of $\chi_{C_3}$ for the corresponding non-interacting states arising from explicit $C_2$-breaking parameter $\beta \neq 0$ in the BM model. We can clearly see from the figure that a relatively small $\chi_{C_3}(BM) \sim 10^{-3}$ in the non-interacting states induces induces a much larger $C_3$ symmetry breaking of almost two orders of magnitude in the $C_2TI$ state. This serves to show that the $C_2TI$ has very large susceptibility to $C_3$ symmetry breaking. In the following, we will refer to this state for positive and negative $\beta$ as $C_3C_2TIy$ and $C_3C_2T lx$, respectively. In addition to this insulating state, there are two distinct $C_2$-preserving semimetallic phases which spontaneously break $C_3$ even for $\beta = 0$.

![Fig. 1. (a) Energies of the solutions of the self-consistent HF equations as a function of the $C_3$ symmetry breaking parameter $\beta$. All energies are measured relative to the state with no-broken symmetry. The degree of $C_3$-breaking measured by $\chi_{C_3}$ (Eq. 7) for the $C_2T$-breaking insulator as a function $\chi_{C_3}$ for the non-interacting system for $0 \leq |\beta| \leq 5 \times 10^{-4}$ are shown in panels (b) and (c) for positive and negative values of $\beta$, respectively.](image-url)
which we denote by $C_3Sx$ and $C_3Sy$, since they have Dirac points along $k_x$ and $k_y$, respectively.

At $\beta = 0$, the energies of the insulating VP/SP and $C_2TI$ states are equal and slightly smaller than the energies of the two semimetallic $C_3$ breaking states. An explanation for this fact is detailed in the supplemental material in the chiral limit where the intrasublattice hopping is switched off $^{[45]}$. In this limit, we can establish rigorous bounds for the energy of the different phases and show that the lowest energy states are the SP/VP and the $C_2TI$ state whose energy is higher by a very small amount. The energies of the $C_3$ states are higher than these two but the energy difference can be shown to be relatively small (compared to the interaction scale) provided that the form factors (Eq. 6) decay quickly enough in $|G|$ and $|k - k'|$, which can be confirmed numerically. This analysis explains why these states are expected to be close in energy, but it is generally insufficient to capture the details of the energy competition which depends sensitively on the intrasublattice hopping $\tilde{w}_0$ and can only be determined numerically.

Once $\beta$ becomes non-zero, the energy of the $C_2T$ breaking state is reduced relative to the VP/SP state. Furthermore, one of the two $C_3$-breaking states (depending on the sign of $\beta$) goes down in energy becoming more energetically favorable to the VP/SP state around $\beta = \pm 3 \times 10^{-4}$. For larger values of $\beta \gtrsim 4 \times 10^{-4}$, the energies of the insulating $C_2T$-breaking phase and the semimetallic $C_2T$-preserving phase approach the same value. This indicates that even very small explicit $C_3$-breaking picks out these two states as the main candidates for the ground state at CN. Assuming that such small explicit $C_3$ symmetry breaking exists in real samples due to strain, our analysis leads to the conclusion that the ground state of TBG at CN is either a $C_2T$-breaking valley Hall insulator or a $C_2T$-symmetric semimetal. Both states strongly break $C_3$ symmetry and are very close in energy.

The possibility of $C_3$ breaking at CN is consistent with several recent reports $^{[37,39]}$, which observed direct evidence of $C_3$ breaking in STM measurements. To check the compatibility of these measurements with our mean field solutions, we compute the DOS for the four possible $C_3$-breaking states (arising for positive or negative values of $\beta$) in Fig. 3b. We see that in all cases the global DOS consists of two broad peaks (which are sometimes further split into two) separated by about 60-80 meV, in agreement with the STM measurements $^{[37,38]}$. The DOS is however, insufficient to distinguish the insulating and semimetallic state, since both have very low DOS close to zero energy. One way to distinguish the two is to compute the local filling fraction defined as $^{[39]}$

$$\nu(r) = 8 \left( \frac{\rho_{LB}(r)}{\rho_{LB}(r) + \rho_{UB}(r)} - \frac{1}{2} \right) \in [-4, 4],$$  

where $\rho_{LB}/UB(r)$ denote the integrated local DOS from the upper layer for the lower/upper band. $\nu(r)$, shown in Fig. 3, exhibits clear $C_3$-symmetry breaking pattern for all the four phases. The patterns for the semimetallic and insulating phases can be distinguished by $C_2$ symmetry which is visibly present in the former but absent in the latter. These patterns are qualitatively similar to those measured in Ref. $^{[39]}$, but seem to differ in some of the details, most notably the fact that $\nu(r)$ vanishes in the vicinity of the AA point. This suggests that the two potential ground states can be easily distinguished based on STM data alone by computing the local filling fraction.

Another compatibility check is to compare the expected sequence of Landau levels generated by our mean field solutions to the experimentally measured ones. In this regard, we note that a pattern of $C_3$ symmetry breaking was recently proposed $^{[40]}$ as an explanation for the unusual sequence of Landau levels ($n_e/n_B = \pm 4, \pm 8, \pm 12, \ldots$) observed for the semimetallic state at CN $^{[11,22]}$. Naively, the two Moiré Dirac cones,
each of which is four-fold degenerate due to spin and valley degrees of freedom, give rise to a Landau level degeneracy of eight. However, in the presence of $C_3$ breaking, the two Dirac points are pushed towards each other so that the two electron pockets at small doping merge into one at the doping is increased. The Fermi surface contours for the lower band in the two $C_3$ breaking semimetals are provided in Fig. 4 showing the two electron pockets corresponding to the two nearby Dirac points quickly merging into a single one for doping around 0.02 (per spin per valley). This doping corresponds to a magnetic field of $\sim 0.5\ T$ in agreement with experimental observations. We note that this conclusion holds regardless of the nature of $C_3$ symmetry breaking, in contrast to the case of weak $C_3$ breaking that requires a particular sense of the breaking for this conclusion. For the $C_2 T$ breaking valley Hall insulator, in addition to the obvious $n_e/n_H = 0$ sequence from the gap, we may expect a similar sequence based on the energy contours shown in Fig. 4. In addition, other sequences at $\pm 2$ may arise if the spontaneously generated sublattice potential has a certain form. However, other effects such as orbital Zeeman effect may change the degeneracy obtained based on Fig. 4. Thus, this case requires an explicit numerical computation for the Landau level spectrum which we leave for future works.

Finally, we propose one additional experimental check for the $C_2 T$-breaking insulating state by investigating the response of the gap to in-plane magnetic field. Since spin symmetry is unbroken, we expect the gap to close with a slope of approximately $2\mu_B$ due to Zeeman splitting. We note that, as pointed out recently in the context of twisted double bilayer graphene, in-plane field can also induce an orbital effect. For the state considered here, this effect turned out to be rather small (see supplemental material) and it only slightly changes the slope of the gap reduction with in-plane field. It is worth mentioning that, although this feature is not unique to the $C_2 T$-breaking valley Hall insulator discussed here, it can be used to exclude competing states such as the spin-polarized insulator.

**Conclusion** — In conclusion, we have performed a momentum-space self-consistent Hartree-Fock analysis to uncover the nature of the symmetry-broken phase in twisted bilayer graphene at charge neutrality. In addition to insulating states corresponding to spin, valley or sublattice polarization, we found two $C_3$-breaking $C_2 T$-symmetric semimetallic solutions. Our main finding is that the existence of very small explicit $C_3$-breaking energetically favors one of these $C_2 T$-symmetric metallic state together with a $C_2 T$-breaking valley Hall insulating states. Both states have roughly the same energy, strongly break $C_3$ symmetry and are consistent with the density of states measured in STM experiments. They can be experimentally distinguished in transport measurements or by comparing space-resolved local filling fractions in STM. We propose these two states as candidates for the insulating and semimetallic states observed in different experiments at CNP and suggest that the competition between the two is settled by small details that are likely sample-dependent. Possible extensions of this work include investigating the insulating states observed at other filling, incorporating the effects of other bands and examining how sensitive our conclusions are to explicit $C_2$ symmetry breaking arising from substrate alignment.

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[33] We follow the standard convention of measuring the filling relative to charge neutrality where the Dirac points of the original graphene sheet reside. Complete filling corresponds to $n_{\nu_T} = 4$ while completely empty $\nu_T = -4$ electrons per moiré unit cell, accounting for both spin and valley degeneracy.

[34] Half filling corresponds to $\nu_T = \pm 2$.


[44] There are also two additional mirror symmetries which exchange the layers which do not play a big role in our analysis.


SUPPLEMENTAL MATERIAL: 
Nematic topological semimetal and insulator in magic angle bilayer graphene at charge neutrality

SINGLE-PARTICLE PHYSICS: BISTRITZER-MACDONALD MODEL

Our starting point is the Bistritzer-MacDonald (BM) model of the TBG band structure [47], which we now briefly review. We begin with two layers of perfectly aligned (AA stacking) graphene sheets extended along the $xy$ plane, and we choose the frame orientation such that the $y$-axis is parallel to some of the honeycomb lattice bonds. Now we choose an arbitrary atomic site and twist the top and bottom layers around that site by the counterclockwise angles $\theta/2$ and $-\theta/2$ (say $\theta > 0$), respectively. When $\theta$ is very small, the lattice form a Moiré pattern with very large translation vectors; correspondingly, the Moiré Brillouin zone (MBZ) is very small compared to the monolayer graphene Brillouin zone (BZ), as illustrated in Fig. S1. In this case, coupling between the two valleys can be neglected. If we focus on one of the two valleys, say $K$, then the effective Hamiltonian is given by:

$$ H_+ = \sum_l \sum_k f_{l}^\dagger(k) h_k(l\theta/2) f_{l}(k) + \left( \sum_k \sum_{i=1}^{3} f_{l}^\dagger(k + q_i) T_i f_{l}(k) + h.c. \right). $$

(S1)

Here, $l = t/b = \pm 1$ is the layer index, and $f_{l}(k)$ is the $K$-valley electron originated from layer $l$. The sublattice index $\sigma$ is suppressed, thus each $f_{l}(k)$ operator is in fact a two-column vector. $h_k(\theta)$ is the monolayer graphene $K$-valley Hamiltonian with twist angle $\theta$:

$$ h_k(\theta) = \hbar v_F \begin{pmatrix} 0 & (k_x - i k_y) e^{i\theta} \\ (k_x + i k_y) e^{-i\theta} & 0 \end{pmatrix}, $$

(S2)

where $v_F = 9.1 \times 10^5$ m/s is the Fermi velocity. Let $K_l$ be the $K$-vector of layer $l$, then $q_1$ is defined as $K_b - K_l$, $q_2 = O_3 q_1$ is the counterclockwise $120^\circ$ rotation of $q_1$, and $q_3 = O_3 q_2$. Finally, the three matrices $T_i$ are given by

$$ T_1 = (1 + \beta) \begin{pmatrix} w_0 & w_1 \\ w_1 & w_0 \end{pmatrix}, \quad T_2 = \begin{pmatrix} w_0 & w_1 e^{-2\pi i / 3} \\ w_1 e^{2\pi i / 3} & w_0 \end{pmatrix}, \quad T_3 = \begin{pmatrix} w_0 & w_1 e^{2\pi i / 3} \\ w_1 e^{-2\pi i / 3} & w_0 \end{pmatrix}, $$

(S3)

where we introduced an explicit $C_3$-breaking parameter $\beta$. We take $w_1 = 110$ meV and $w_0 = 82.5$ meV. The difference between $w_0$ and $w_1$ reflects the effect of lattice relaxation.

One intuitive way of thinking about this effective Hamiltonian is to imagine a honeycomb lattice of Dirac points in the momentum space, as shown in Fig. S2, where the two sublattices correspond to the two layers. A Dirac point at momentum $q$ contributes a diagonal block $h_{k-\mathbf{q}}(\pm \theta/2)$ to the Hamiltonian for the MBZ momentum $k$, where the sign is determined by the sublattice that $q$ belongs to. The off-diagonal blocks $T_i$ are nothing but the nearest-neighbor couplings of these Dirac points.

Real Space

Momentum Space

![Real Space vs Momentum Space](image)

FIG. S1. Bravais lattice vectors, reciprocal lattice vectors and Brillouin zones for both monolayer and Moiré lattices of twisted bilayer graphene. In the real space (left) panel, we also show the underlying Moiré pattern structure.

When the twist angle is near the magic angle $\theta = 1.05^\circ$, two isolated flat bands per spin and valley appear near the charge neutrality (CN) Fermi energy, shown in Fig. S2b. These two bands are the focus of the current work.

The single particle Hamiltonian within each valley $H_{\pm}$ is invariant under the following symmetries

$$ C_3 c_k C_3^{-1} = e^{-\frac{2\pi}{3} i \tau_2 \sigma_z c_l}, \quad (C_2 T) c_k (C_2 T)^{-1} = \sigma_x c_k, \quad M_y c_k M_y^{-1} = \sigma_x \mu_x c_M k, $$

(S4)
In addition, the two valleys are related by time-reversal symmetry given by
\[ \mathcal{T} c_k \mathcal{T}^{-1} = \tau_x c_{-k}. \] (S5)
Here, \( \sigma, \tau \) and \( \mu \) denote the Pauli matrices in sublattice, valley and layer spaces, respectively.

PROJECTING THE INTERACTION ONTO THE FLAT BANDS

In the following, we derive the form of the interaction when projecting onto the two flat bands. Since these two bands have a Wannier obstruction, we can only write such projected interaction in \( k \)-space. Let \( c^\dagger_{\mu}(k) \) be the creation operator for the energy eigenstate in the band structure with internal flavor \( \mu \) and band index \( n \), where \( \mu = (\tau, s) \) is a collective index including both valley \( \tau = \pm \) and spin \( s = \uparrow / \downarrow \), and \( n = 1, 2 \) represents the lower and upper bands, respectively. Also let \( f^\dagger_{\mu,l}(q) \) be the “elementary” continuous fermion with monolayer momentum \( q \), flavor \( \mu = (\tau, s) \) and \( I = (l, \sigma) \) representing layer and sublattice, then \( c^\dagger \) and \( f^\dagger \) are related to each other by the \( k \)-space wave functions as follows:
\[
c^\dagger_{\mu,n}(k) = \sum_{G,I} u_{\tau,n;G,I}(k) f^\dagger_{\mu,I}(k + G), \quad \text{(S6)}
\]
where \( G \) is a Moiré reciprocal lattice vector. In the above expression, we are already using the fact that the wave functions are spin-independent. Once we choose a gauge of \( u_{\tau,n;G,I}(k) \) for all \( k \) in some MBZ, \( c^\dagger(k) \) are defined in terms of the \( f^\dagger(q) \) for those \( k \), and whenever necessary, we define \( c^\dagger(k + G) = c^\dagger(k) \) for any reciprocal lattice vector \( G \), which is equivalent to defining \( u_{\tau,n;G,I}(k + G_0) = u_{\tau,n;G+G_0,I}(k) \). Note that the momentum argument for \( f^\dagger \) is unconstrained since we are using the continuum theory for monolayers of graphene. We choose the normalization \( \{f_{\mu,l}(q), f^\dagger_{\mu',l',I}(q')\} = \delta_{\mu\mu'}\delta_{II'}\delta_{qq'} \) (suppose the system size is finite), and \( \langle u_{\tau,n}(k)|u_{\tau',n'}(k') \rangle := \sum_{G,I} u_{\tau,n;G,I}(k) u^*_{\tau',n';G,I}(k) = \delta_{\tau\tau'}\delta_{nn'} \), which imply \( \{c_{\mu,n}(k), c^\dagger_{\mu',n'}(k')\} = \delta_{\mu\mu'}\delta_{nn'}\delta_{kk'} \) when \( k, k' \) are confined in the MBZ. For the purpose of projecting the interaction into these two bands, it is convenient to introduce the form factor notation:
\[
\lambda_{mn,\tau;G}(k_1, k_2) := \langle u_{\tau,m}(k_1)|u_{\tau,n}(k_2 + G) \rangle. \quad \text{(S7)}
\]
The form factors satisfy
\[
\lambda_{mn,\tau;G}(k_1, k_2) = \lambda_{nm,\tau;G}(k_2, k_1)^* \quad \text{(S8)}
\]
just from the definition, and also has the property
\[
\lambda_{mn,\tau;G}(k_1, k_2) = \lambda_{nm,\tau;G}(-k_2, -k_1) \quad \text{(S9)}
\]
due to the time-reversal symmetry.
The interaction Hamiltonian is given by

$$H_{\text{int}} = \frac{1}{2A} \sum_{\sigma, \sigma', \tau, \tau'} \sum_{q} V(q) : \rho_{\sigma, \tau, q} \rho_{\sigma', \tau', -q} : \quad (S10)$$

where $A$ is the total area of the system and $V(q)$ is the momentum space interaction potential, related to the real-space one by $V(q) := \int d^2r V(r) e^{-iq \cdot r}$. Depending on the number of gates, $V(q)$ takes the following form in the SI units:

$$V(q) = \frac{e^2}{2\epsilon_0 q} \begin{cases} (1 - e^{-2qd_s}), & \text{(single-gate)} \\ \tanh(qd_s), & \text{(dual-gate)} \end{cases} \quad (S11)$$

where the screening length $d_s$ is nothing but the distance from the graphene plane to the gate(s). Projecting onto the two narrow bands, this Hamiltonian has the form

$$H_{\text{int}} = \frac{1}{2A} \sum_{\sigma, \sigma', \tau, \tau'} \sum_{n_1, n_2, n_3, n_4} \sum_{k_1, k_2, k \in \text{BZ}} \lambda_{n_1, n_2; \tau}(k_1, k_1 + k + G) V(G + k) \lambda_{n_4, n_3; \tau'}(k_2, k_2 + k + G)$$

$$\times c_{n_1, \sigma, \tau}(k_1) c_{n_3, \sigma', \tau'}^\dagger(k_2 + k)c_{n_4, \sigma', \tau'}(k_2) c_{n_2, \sigma, \tau}(k_1 + k). \quad (S12)$$

**HARTREE-FOCK ANALYSIS IN THE CHIRAL LIMIT**

The chiral limit of the BM model is obtained by switching off the $w_0$ term in $(S3)$ \cite{33}. In this limit, the bands become exactly flat at the magic angle and the eigenstates of the Hamiltonian have a simple form similar to the Landau levels on a torus. In the following, we will assume that we are slightly off the magic angle so that we can still define the upper/lower bands (apart from the $K$ and $K'$ points) while at the same time having a very small bandwidth which can be neglected compared to the interaction term. In the chiral limit, the single particle Hamiltonian anticommutes with the chiral (sublattice) symmetry operator given by $\Gamma = \sigma_z$.

Since chiral symmetry anticommutes with the Hamiltonian, it exchanges positive and negative energies, thus

$$\Gamma u_{1, k} = e^{i\phi_k} u_{2, k}, \quad \Gamma u_{2, k} = e^{-i\phi_k} u_{1, k} \quad (S13)$$

The phase $\phi_k$ can be removed by a gauge transformation of the form $e^{i\gamma x}$, where $\gamma_{x, y, z}$ are the Pauli matrices in the band space, leading to $\Gamma = \gamma_z$. This leads to

$$\lambda_{11; \tau, G}(k, k') = \lambda_{22; \tau, G}(k, k') = \lambda_{\tau, G}(k, k'), \quad \lambda_{12; \tau, G}(k, k') = \lambda_{21; \tau, G}(k, k') = \tilde{\lambda}_{\tau, G}(k, k') \quad (S14)$$

Similarly, the action of $C_2T$ is given by

$$C_2 T u_{1, k} = e^{i\phi_{1, k}} u_{1, k}^*, \quad C_2 T u_{2, k} = e^{i\phi_{2, k}} u_{2, k}^* \quad (S15)$$

since $C_2T$ anticommutes with $\Gamma$ in the original basis, it also has to anticommute with it in the band basis, which implies that $\phi_{2, k} = \phi_{1, k} + \pi$. We can remove the phase $\phi_k$ by a gauge transformation with the form $e^{i\gamma x}$ leading to $C_2 T = \gamma_z \mathcal{K}$ with $\mathcal{K}$ denoting complex conjugation. This leads to

$$\lambda_{\tau, G}(k, k') = \lambda_{\tau, G}^*(k, k'), \quad \tilde{\lambda}_{\tau, G}(k, k') = -\tilde{\lambda}_{\tau, G}^*(k, k') \quad (S16)$$

The form of $C_3$ and $M_y$ in the band basis are generally complicated and depend on $k$.

We now investigate the Hartree-Fock solutions by looking for the minima of the Hartree-Fock energy rather than solving the self-consistency condition. This can be seen as a variational approach where we look for the local minima of the energy within the space of single-particle (slater determinant) states.

The Hartree-Fock energy is defined in terms of the order parameter

$$P_{\alpha\beta}(k) = \langle c_{\alpha}^\dagger(k) c_{\beta}(k) \rangle \quad (S17)$$

where $\alpha, \beta$ range over spin, valley and band indices. For an insulator or a semimetal, the number of filled states is $k$ independent and equal to the filling $\nu$ (in this section, we define the filling relative to the empty filling which means it is related to the filling
\( \nu_T \) defined relative to CN in the main text as \( \nu = \nu_T + 4 \). This means that the order parameter \( P_k \) is a projector satisfying

\[
P(k)^2 = P(k) = P^\dagger(k), \quad \text{tr} \ P(k) = \nu = \nu_T + 4
\]

where \( \nu \) is the filling relative to the empty bands.

The Hartree-Fock energy can then be written as (using properties of the chiral limit)

\[
E_{HF} = E_H + E_F
\]

\[
E_H = \frac{1}{2A} \sum_{G,k,k'} V_G \text{tr} P(k) \Lambda^1_G(k,k) \text{tr} P(k') \Lambda_G(k',k')
\]

\[
E_F = -\frac{1}{2A} \sum_{G,k,k'} V_{G+k'-k} \text{tr} P(k) \Lambda^1_G(k,k') P(k') \Lambda_G(k,k')
\]

where we defined the form factor matrix \( \Lambda_G(k,k') \) in terms of the combined index \( \alpha = (s, \tau, n) \) for spin, valley, and band as

\[
[\Lambda_G(k,k')]_{\alpha,\alpha'} = \delta_{s,s'} \delta_{\tau,\tau'} \delta_{n,n'} \Lambda_G(k,k') = \delta_{\tau,\tau'} [\lambda_{\tau,G}(k,k')\gamma_0 + \check{\lambda}_{\tau,G}(k,k')\gamma_2]_{n,n'}
\]

which satisfies \( \Lambda_G(k,k')^T = \Lambda_G^*(k,k') \). The form factors decay in the separation \( G + k' - k \) with a characteristic scale \( \kappa \) which is typically smaller than the size of the Brillouin zone. This means that the sums in the Hartree and Fock terms are dominated by the \( G = 0 \) term. For the Hartree term, this equals \( \nu V(0)N \) and is independent of the order parameter \( P(k) \). Thus, the main distinction between different symmetry broken states comes from the Fock term.

We now consider possible types of symmetry-broken orders at integer fillings \( \nu \). The order parameter \( P(k) \) can generally be written as

\[
P(k) = \frac{\nu}{2} + Q(k), \quad \text{tr} \ Q(k) = 0
\]

Due to the structure of the form factor in valley space, it will be convenient to classify the different symmetry-broken phases according to their structure in valley space into three types of states:

- **Valley unpolarized states**: these are phases for which \( P(k) = \text{diag}(P_+(k), P_-(k))_r \) with \( P_\pm(k) \) related by time-reversal symmetry \( P_-(k) = P_+(-k)^* \). These states preserve both time-reversal and U(1) valley symmetries.

- **Valley polarized states**: these are characterized by broken time-reversal symmetry and unbroken U(1) valley symmetry. They are characterized by an order parameter with the form \( P(k) = \text{diag}(P_+(k), P_-(k))_r \) with \( P_-(k) \neq P_+(-k)^* \). In fact, for an insulator or semimetallic phase, the valley-resolved order parameters satisfy \( \text{tr} \ P_\pm(k) = \nu_\pm \) with \( \nu_+ + \nu_- = \nu \) and \( \nu_+ \neq \nu_- \).

- **Intervalley coherent order**: these are characterized by broken U(1) valley symmetry manifested in off-diagonal valley components \( \tau_{\tau',\nu} \) in the order parameter.

**Valley unpolarized states**

For valley-unpolarized states, it suffices to focus on a single valley since the other valley can be obtained from it by time-reversal symmetry. The Fock energy is given by

\[
E_F = -\frac{1}{2A} \sum_{k,k',G} V_{G+k'-k} \text{tr} P_+(k) \Lambda^1_{+,G}(k,k') P_+(k') \Lambda_{+,G}(k,k')
\]

Let us start with the Fock term which typically gives the larger contribution. We note that \( \langle A, B \rangle = \text{tr} AB \) defines a positive definite inner product on the space of hermitian matrices. Using Cauchy-Schwarz inequality, we get

\[
E_F \geq -\frac{1}{2A} \sum_{k,k',G} V_{G+k'-k} \sqrt{\text{tr} \ P_+(k) \text{tr}[\Lambda^1_{+,G}(k,k') P_+(k') \Lambda_{+,G}(k,k')]^2}
\]
We now note that
\[ \Lambda_{r,G}(k,k') \Lambda_{r,G}^\dagger(k,k') = \Lambda_{r,G}^\dagger(k,k') \Lambda_{r,G}(k,k') = \gamma_0 |\Lambda_{r,G}(k,k')|^2 + |\tilde{\Lambda}_{r,G}(k,k')|^2 = \gamma_0 |\Lambda_{r,G}(k,k') + \tilde{\Lambda}_{r,G}(k,k')|^2 \]
where the last equality follows from (S16). This implies that we can write \( \Lambda_{r,G}(k,k') \) as
\[ \Lambda_{r,G}(k,k') = R_{r,G}(k,k') U_{r,G}(k,k'), \quad U_{r,G}(k,k') U_{r,G}^\dagger(k,k') = 1, \quad R_{r,G}(k,k') = (|\Lambda_{r,G}(k,k')|^2 + |\tilde{\Lambda}_{r,G}(k,k')|^2)^{-1/2} \]
Substituting in (S25) yields
\[ E_F \geq -\frac{\nu}{2A} \sum_{k,k'} V_G \tilde{F}_{k-k'} R_{r,G}(k,k') \]
This inequality is satisfied if and only if \( P_+(k') \) is parallel to \( \Lambda_{r,G}(k,k') P_+(k) \Lambda_{r,G}^\dagger(k,k') \) for every \( k, k' \) and \( G \). This means
\[ P_+(k') = U_{+G}(k,k') P_+(k) U_{+G}^\dagger(k,k') \Rightarrow Q_+(k') = \lambda_{+G}(k,k') Q_+(k) U_{+G}^\dagger(k,k') \]  
We notice that a similar inequality can be derived for the Hartree term
\[ E_H \geq \frac{\nu^2}{2A} \sum_G V_G |\sum_k \lambda_{G}(k,k)|^2 \]
which is fulfilled whenever \( \text{tr} Q_+(k) \Lambda_{+G}(k,k) = 0 \).

A \( k \)-independent order parameter which only breaks SU(2) spin rotation obviously fulfills both constraints, thereby saturating both bounds. In the following, we will focus on phases which has a structure in the band space, breaking \( C_2T \) or \( C_\beta \) symmetries.

**\( C_2T \) breaking**

A \( C_2T \) breaking solution to Eq. (S29) is obtained by taking \( Q_k \) to be \( k \)-independent proportional to \( \gamma_x \) (recall that \( C_2T = \gamma_x K \)). At charge neutrality \( \nu = 4 \), this yields a gapped phase whereas at half-filling, it requires additional SU(2) symmetry breaking to yield a gapped phase. Such state, however, does not saturate the Hartree bound. Its Hartree energy exceeds the bound by
\[ E_{H,C_2TB} = \frac{\nu^2}{2A} \sum_G V_G |\tilde{\lambda}_{+G}(k)|^2 \]
which is very small since the summand vanishes at \( G = 0 \) and decays rapidly with \( G \). The actual energy minimum within the same energy sector as this \( C_2T \)-breaking state has to be less than or equal to the energy of the uniform state we considered here. Thus, the energy difference between SP and \( C_2T \) state can be bounded by
\[ 0 \leq E_{C_2TB} - E_{SP} \leq \frac{\nu^2}{2A} \sum_G V_G |\tilde{\lambda}_{+G}(k)|^2 \]

In fact, such uniform solution is very close to the actual solution obtained self-consistently in the main text as shown in Fig. S3. We note that the inclusion of the intrasublattice hopping \( w_0 \) and \( C_3 \)-breaking \( \beta \) changes the relative energy between the two states making the \( C_2T \) state lower in energy, but the difference will remain small as shown in the main text.

**\( C_\beta \) breaking**

A \( k \)-independent order parameter which does not break \( C_2T \) cannot satisfy Eq. (S29). However, there could still be solutions which are \( k \)-dependent. A general \( C_2T \)-invariant solution is given by
\[ Q_+(k) = \gamma_z \cos \alpha_k + \gamma_y \sin \alpha_k = \gamma_z e^{i\alpha_k \gamma_x} \]
In the following, we look for solutions which satisfy (S29) for the terms which give the largest contribution to the energy sum in (S25) which correspond to \( G = 0 \) and \( |k - k'| \leq \bar{\kappa} \). In this limit, we find that \( U_{+,0}(k,k') \approx \gamma_0 \) vicinity of any point apart.
from K and K’. This means that we can choose any $k$-independent value for $\alpha_k$. However, in the vicinity of the K or K’ points, the form factor matrix is given by $U_{\gamma_z}(k, k’) = e^{i/2(\phi_k - \phi_{k’})}/2$, where $\phi_k$ represents the angle between $k$ (measured relative to the K or K’ points) and the x-axis. This means that, in the vicinity of the K or K’ points, the choice $\alpha_k = \phi_k$ satisfies Eq. S29. This seems to suggest that the choice $\alpha_k = \phi_k - K + \phi_{k’} - K’$ will satisfy the bound everywhere (for $G = 0$ and $|k - k’| \leq \kappa$).

We notice, however, that such solution is not consistent with the requirement that $\phi_k$ is periodic in $k$. The reason is that the Dirac points at K and K’ has the same chirality, thus the phase of $\alpha_k$ has the same winding about both points leading to a total winding of 2 across the border of the Brillouin zone which is inconsistent with periodicity. To resolve this issue, there has to be a point $k_0$ where the winding of the phase $\alpha_k$ is −2. In the vicinity of this point, the Fock energy will not saturate the bound and the order parameter is discontinuous. The size of this region is relatively small (of the order $\kappa^2$), thus the resulting state is very close in energy to the bound (S25). The main mechanism for the energy reduction in this state is the cancellation of the Berry curvature of the form factors close to the K and K’ points and concentrating it close to a single momentum space point. In addition, this state saturates the Hartree bound by construction.

We notice that the order parameter $Q_{\pm, k}$ is discontinuous at K, K’ and $k_0$. The discontinuity at K and K’ is an artefact of the band basis which is discontinuous at these two points and it cancels against the discontinuity of the form factors leading a continuous projector when expressed in the original basis. On the other hand, the discontinuity at $k_0$ corresponds an actual singularity for the projection operator onto the filled bands at this point indicating that the corresponding phase is a semimetal. This phase can be identified with the $C_3$-breaking semimetal observed in the numerics. This can be verified by comparing the numerically obtained order parameter and with a simple order parameter $\alpha_k = 2\phi_k - \phi_{k-K} - \phi_{k-K’}$ corresponding to the choice $k_0 = \Gamma$ as shown in Fig. S3.

![FIG. S3. (a) $\gamma_z$ component of the $C_2T$ order parameter, $\frac{1}{2} \text{tr} P(k)\gamma_z$, obtained from solving the self-consistent equation numerically (with $w_0 \neq 0$). We see that it is relatively uniform over the BZ consistent with our ansatz. (b) $\gamma_z$ component for the $C_3$-breaking order $\frac{1}{2} \text{tr} P(k)\gamma_z$ obtained from solving the self-consistent equation numerically (with $w_0 \neq 0$). (c) $\gamma_z$ component of the order parameter for a simple ansatz for the order parameter in the chiral limit given by $-\frac{1}{2} \cos \alpha_k$, $\alpha_k = 2\phi_k - \phi_{k-K} - \phi_{k-K’}$].

Valley polarized states

The discussion of valley polarized states is very similar to the previous section where the problem is solved independently in each valley. The bounds derived are the same as those derived in the previous section, Eq. S25 and S30. At charge neutrality, a completely valley polarized state is a possible ground state. At half-filling, valley polarization could coexist with the spin-polarized, $C_2T$ breaking or $C_3$ breaking states discussed in the previous section.

Intervalley coherent states

We now consider states which break U(1) valley symmetry. For simplicity, we will focus on states which do not break time-reversal. The case of time-reversal symmetry breaking can be addressed similarly. The projector for an IVC state can be split into a diagonal and off-diagonal component in valley space

$$P(k) = P_d(k) + P_o(k), \quad P_d(k)^2 + P_o(k)^2 = P_d(k),$$

(S34)
In terms of valley resolved blocks of $P(k)$, i.e.,

$$P = \begin{pmatrix} P_+ & P_{12} \\ P_{21} & P_- \end{pmatrix},$$  \tag{S35}

the second condition can be written as

$$P_+^2 + P_{12}P_{21} = P_+, \quad P_-^2 + P_{21}P_{12} = P_-.$$  \tag{S36}

Since the form factors are diagonal in valley space, the Fock energy can be written as a sum of a term with only diagonal part and one with only off-diagonal parts as

$$E_F = -\frac{1}{2A} \sum_{G,k,k'} V_{G+k'-k} \text{tr}[P_o(k)\Lambda_G^+(k,k')P_o(k')\Lambda_G(k,k') + P_o(k)\Lambda_G^+(k',k)P_o(k')\Lambda_G(k,k')]$$

$$\geq -\frac{1}{2A} \sum_{G,k,k'} V_{G+k'-k}[R_+,G(k,k') \text{tr} P_o(k) + R_-,G(k,k') \text{tr} P_o(k)]$$

$$\geq -\frac{1}{2A} \sum_{G,k,k'} V_{G+k'-k}[R_+,G(k,k') \text{tr} (P_+ - P_{12}(k)P_{21}(k)) + R_-,G(k,k') \text{tr} (P_- - P_{21}(k)P_{12}(k))]$$

$$= -\frac{\nu}{2A} \sum_{G,k,k'} V_{G+k'-k}R_+,G(k,k') + \frac{1}{4A} \sum_{G,k,k'} V_{G+k'-k}(R_+,G(k,k') - R_-,G(k,k'))^2 \text{tr} P_o(k)^2,$$  \tag{S37}

where time reversal symmetry is used to obtain the last line. Thus, the Fock energy for the IVC is larger than the energy bound for the valley polarized or unpolarized phases by an amount which is proportional to the valley off-diagonal part of the order parameter. The energy difference in (S37) is generally not small and receives contribution from $G = 0$. This means the IVC ordering is always energetically unfavorable and justifies why it was not included in our numerical self-consistent approach.

**EFFECT OF IN-PLANE MAGNETIC FIELD**

To study the effect of the in-plane field, we choose the gauge $A_z = -(ld/2) \hat{z} \times B$ for the two layers, with $d = 3.42$ Å being the interlayer distance. Such gauge choice preserves the two-dimensional translation symmetry since it is just a constant within each layer. Thus, to leading order, the change of the structure due to the orbital effect can be written as

$$\delta\xi_{n,\tau}(k,B) = \mu_B g_{n,\tau}(k) \cdot B,$$  \tag{S38}

where $g_{n,\tau}(k)$ is a $k$-dependent orbital $g$-factor. Following Ref. [21], we compute $g_{n}(k)$ by taking the expectation value of the term proportional to $B$ in the minimally coupled BM model leading to

$$g_{n,\tau}(k) = g_0 \langle u_{n,\tau,k} | (-\sigma_y, \tau \sigma_x) | u_{n,\tau,k} \rangle$$  \tag{S39}

with $u_{n,\tau,k}$ denoting the eigenstates of the BM Hamiltonian and $\sigma$ and $\mu$ denoting the Pauli matrices in the sublattice and layer spaces, respectively. $g_0 := e\nu F d/(2\mu B) = 2.08$ is a dimensionless constant ($\nu F$ being the Fermi velocity of monolayer graphene) measuring the strength of the in-plane orbital effect which is comparable to the electron spin $g$-factor $g_s \approx 2$. We note that $g_{n,\tau}(k)$ vanishes at the $\Gamma$ point as long as $C_3$ symmetry is broken.

At CN, the insulating solutions are the SP, VP and $C_2T$-breaking states. Without any strain, in all these cases, the maximum of the filled bands and the minimum of the empty bands occur at the $\Gamma$ point where the orbital $g$-factor vanishes due to the $C_3$ symmetry. Thus, for experimentally accessible magnetic fields ($|B| < 10$ T), the orbital effect does not play a role. Therefore, the only effect of in-plane field comes from the spin Zeeman term, which linearly increases the gap of the SP states and decreases the gaps of the VP and $C_2T$-breaking states with a slope equal to $0.1$ meV/T. In the presence of strain, the $C_3C_2T \epsilon_x, y$ states largely break the $C_3$ symmetry, thus there can be a nonzero orbital effect. In Fig. [S4] we plot the gaps of the $C_3C_2T \epsilon_x, y$ states.
FIG. S4. Gaps of the $C_3C_2TI_x$ (left) and $C_3C_2TI_y$ (right) states as functions of in-plane magnetic fields applied in $\pm x$ or $\pm y$ directions. In both cases, the $+x$ and $+y$ curves overlap with the $-x$ and $-y$ curves, respectively.

as functions of in-plane fields applied in the $\pm x$ or $\pm y$ directions. The spin Zeeman effect still dominates and reduces the gaps, but a small anistropy is generated due to the orbital $g$-factor. For the VP/SP states, small $C_3$ breaking has negligible effect on the $g$ factor and the energy spectrum, leading to very small orbital effect.